Precision OCXO OH4 Series



2111 Comprehensive Drive Aurora, Illinois 60505 Phone: 630-851-4722 Fax: 630-851-5040

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Description:

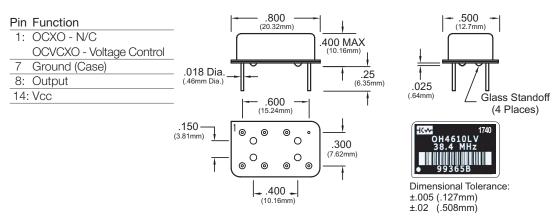
The Connor-Winfield OH4
Series, 14 Pin DIP Oven
Stabilized Crystal Controlled
Oscillators (OCXO) series,
and Oven Stabilized Crystal
Controlled Voltage Controlled Oscillators
(OCVCXO) series, are designed for use in
applications requiring stabilities of ±5ppb to
±100ppb. The OH4 series is also designed for
compliance to ITU-T G.8262 Options 1 and 2,
and ITU-T G.8263.

Features:

- OCXO Fixed Frequency
- OCVCXO Voltage Controlled
- Frequencies Range: 6.4 MHz to 40 MHz Higher Frequencies available upon request
- 3.3V or 5.0V Operation
- LVCMOS, HCMOS or Sinewave Output
- Frequency Stabilities Available: ±5ppb; ±10ppb; ±20ppb; ±25ppb ±50ppb, or ±100ppb
- Temperature Ranges Available:
 0 to 70°C, -20 to 70°C, -20 to 75°C,
 -40 to 70°C, or -40 to 85°C
- Low Phase Noise
- 14 Pin DIP Package
- RoHS Compliant / Lead Free

Pin Connections

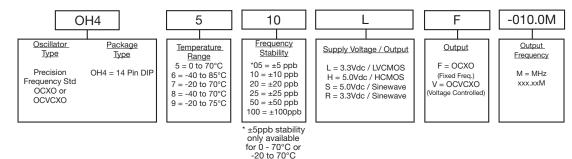
14 Pin DIP Package



RoHS

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Ordering Information





Aurora, Illinois 60505

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Absolute Maximum Ratings

Parameter	Minimum	Nominal	Maximum	Units	Notes
Storage Temperature	-55	-	125	°C	
Supply Voltage (Vcc)					
3.3V LVCMOS	-0.5	-	4.5	Vdc	
5.0V HCMOS / Sinewave	-0.5	-	7.0	Vdc	
Control Voltage (Vc)					
3.3V LVCMOS	-0.5	-	4.5	Vdc	
5.0V HCMOS / Sinewave	-0.5	-	7.0	Vdc	

Operating Specifications

Parameter	Minimum	Nominal	Maximum	Units	Notes
Frequency Calibration	-0.3	-	0.3	ppm	1, 4, 9,
Frequency Stability	*05: ±5; 10: ±1	0; 20: ±20; 50: ±	£50; 100: ±100	ppb	2
Frequency vs Change in Supply Voltage	-10	-	10	ppb	3
Aging Daily	-5	-	5	ppb	4
Aging 1st Year	-0.3	-	0.3	ppm	
Total Frequency Tolerance (20 years)	-1.5	-	1.5	ppm	5, 10
Supply Voltage (Vcc)					
3.3V LVCMOS	3.13	3.3	3.47	Vdc	
5.0V HCMOS / Sinewave	4.75	5.0	5.25	Vdc	
Supply Power (0 to 70°C)	-	-	1.4	Watts	
Supply Power (-40 to 85°C)	-	-	2.2	Watts	
Phase Jitter (BW = 10KHz to Fo/2)	-	-	1	ps RMS	
Period Jitter	-	-	5	ps RMS	
Allan Variance (1 second)	-	5.0E-11	-		
SSB Phase Noise at 10Hz offset	-	-100	-	dbc/Hz	6
SSB Phase Noise at 100Hz offset	-	-120	-	dbc/Hz	6
SSB Phase Noise at 1kHz offset	-	-140	-	dbc/Hz	6
SSB Phase Noise at 10kHz offset	-	-150	-	dbc/Hz	6
Start-Up Time Oscillator	-	-	35	ms	
Warm-Up Time	-	-	3	Minutes	7

OCVCXO Characteristics

Parameter	Minimum	Nominal	Maximum	Units	Notes
Control Voltage Range:(Vc)					
3.3V LVCMOS	0.30	1.65	3.0	Vdc	
5.0V HCMOS / Sinewave	0.50	2.50	4.50	Vdc	
Frequency					
3.3V LVCMOS at Vc=0.3 Vdc	-	-7	-5	ppm	8
3.3V LVCMOS at Vc=3.0 Vdc	5	7	-	ppm	8
5.0V HCMOS /Sinewave at Vc=0.5Vdc	-	-7	-5	ppm	8
5.0V HCMOS /Sinewave at Vc=4.5Vdc	5	7	-	ppm	8
Slope of Frequency Adjust					
3.3V LVCMOS	3.7	-	-	ppm/V	
5.0V HCMOS /Sinewave	2.5	-	-	ppm/V	
Imput Impedance	100K	-	-	Ohms	

- 1. Initial calibration @ 25C. OCVCXO model Vc = Nominal.
- 2. Frequency stability vs. Change in temperature, referenced to 25C.
- 3. Frequency stability per 5% change in supply voltage.
- At the time of shipment after 48 hours of operation.
- 5. Inclusive of calibration, operating temperature range, supply voltage change, shock and vibration 20 years aging, OCVCXO models Vc = Nominal.
- 6. Typical phase noise, results will vary depending on center frequency. The phase noise shown are typical for 20 MHz.
- 7. Measured @ 25C, within 3 minutes, the unit will be within +/-0.1ppm of its reference frequency, measured after 30 minutes of continuous operation at a stable 25C.
- 8. OCVCXO models pullability referenced to Fo @ 25°C, Positive Transfer Characteristics
- 9. Initial calibration @ 25C. OCVCXO model Vc = Nominal.
- 10. Inclusive of calibration, operating temperature range, supply voltage change, shock and vibration 20 years aging, OCVCXO models Vc = Nominal.

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LVCMOS Output Characteristics

Parameter	Minimum	Nominal	Maximum	Units	Notes
Load	-	15	-	pF	
Voltage: 3.3V LVCMOS					
High (Voh)	2.60	-	-	Vdc	
Low (Vol)	-	-	0.40	Vdc	
Voltage: 5.0V HCMOS					
High (Voh)	Vcc-0.5	-	-	Vdc	
Low (Vol)	-	-	0.40	Vdc	
Current					
High (loh)	-4	-	-	mA	
Low (lol)	-	-	4	mA	
Duty Cycle at 50% of Vcc	45	50	55	%	
Rise / Fall Time: 10% to 90%	-	-	6.5	ns	

Sinewave Output Characteristics

Parameter	Minimum	Nominal	Maximum	Units	Notes
Load	-	50	-	Ohms	
Output Power					
(Vcc=3.3V)	3	-	-	dBm	
(Vcc=5.0V)	6	-	-	dBm	
Harmonics	-	-	-30	dBc	_
Spurious	-	-	-80	dBc	

Package Characteristics

OH4-Series DIP Package

Vcc

POWER SUPPLY

14 Pin DIP Hermetically Sealed Grounded Welded Package

14 Pin DIP Package Environmental Characteristics

ENVIRONMENTAL CHARACTERISTICS

_ remperature Cycle:	Per Mile-510-883, Method 1010, Condition B55°C to 125°C, 300 cycles, 10 minute dwell, 1 minute transition.
Gross Leak Test:	Per MIL-STD-202, Method 112, Condition D. No Bubbles in flourinert (FC-43) at125°C ±5°C for 20 seconds

SOLDERING

Pin Solderability: Per MIL-STD-883, Method 2003. 8 hour steam age prior to 254°C ±5°C Solder ot dip, 95% Coverage.

Resistance to Solder Heat: Per MIL-STD-202, Method 210, Condition C. Wave: Topside board-mount product. 260°C ±5°C for 20 seconds

PROBE

FREQ

MECHANICAL CHARACTERISTICS

Vibration: Per MIL-STD-202, Method 204, Condition A. 10G's peak, 10Hz to 500Hz, 15 minute cycles 12 times each

nernendicular axis

Shock: Per MIL-STD-202, Method 213, Condition F 1500G's, 0.5ms, half sine, 3 shocks per direction.

Moisture Resistance: Per MIL-STD-202, Method 106. 95% RH @ 65°C, 10 cycles 10°C to 65°C.

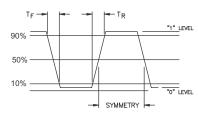
Test Circuit

OCXO = N/C OCVCXO = VC

*15 pF for CMOS Load

50 Ohms for Sinewave Load

CMOS Output Waveform



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GROUND

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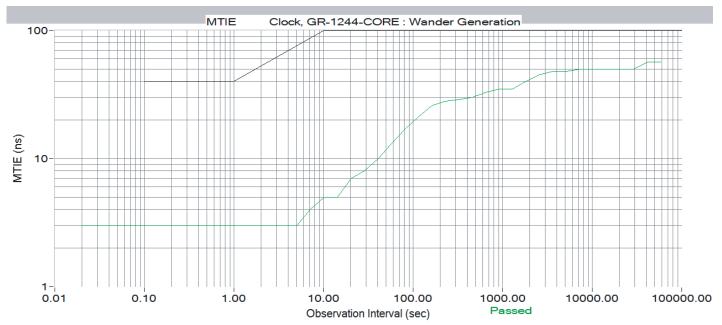


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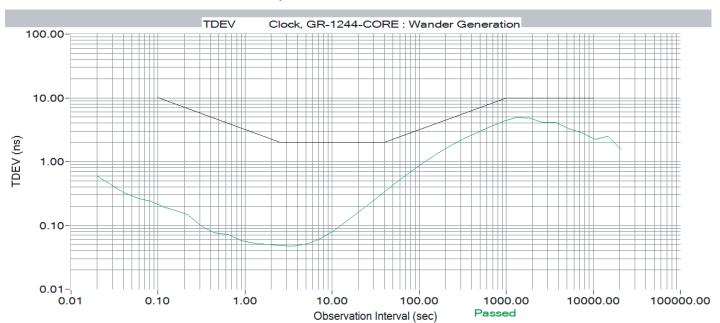
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OH4610LF-020.0M MTIE per Stratum 3E (OCXO is covered) Loop Bandwidth = 0.0016 Hz



OH4610LF-020.0M TDEV per Stratum 3E (OCXO is covered)

Loop Bandwidth = 0.0016 Hz



Revision History

Revision	Date	Note
00	09/30/14	New issue
06	08/08/19	Added ±100ppb Frequency Stability
07	10/15/19	Added ±25ppb Frequency Stability

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